

6. Quantum nanostructures

6.1 Quantum wells

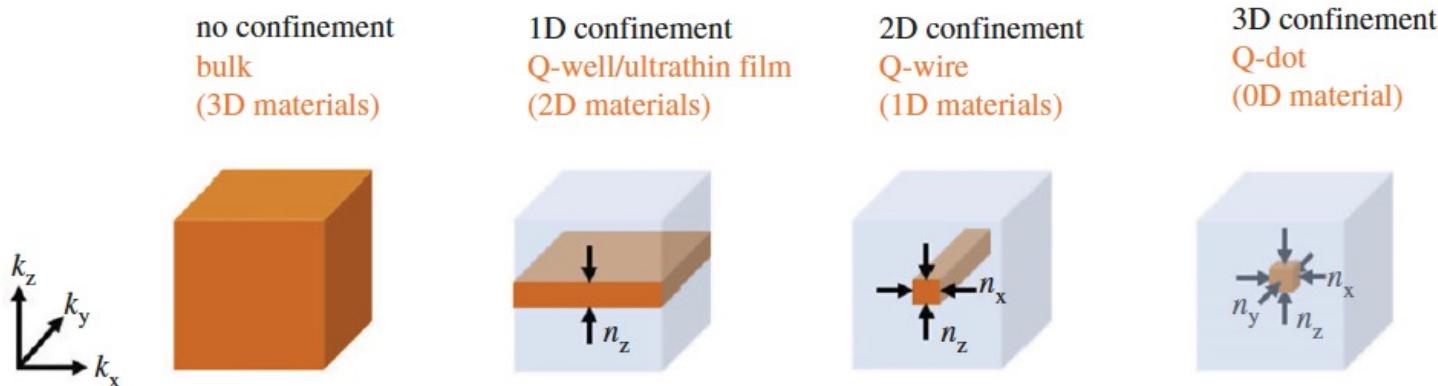
Topics of this lecture:

- Quantum confinement
- Quantum wells
- Absorption in quantum wells
- Applications of quantum wells

- Quantum dots
- Absorption in quantum dots
- Applications of quantum dots, part I

Quantum confinement

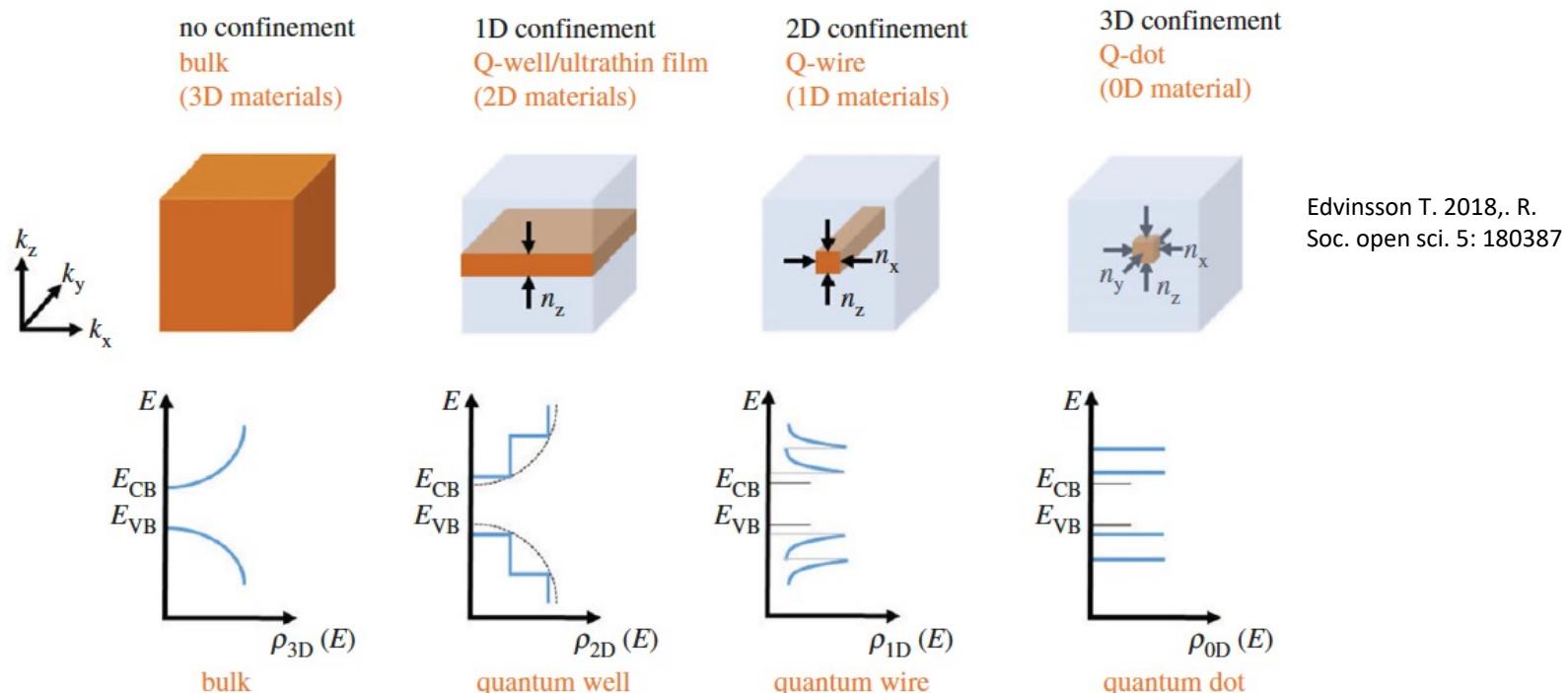
Edvinsson T. 2018., R.
Soc. open sci. 5: 180387



- In general, optical/electronic properties of solids do not depend on size
Ex: Ruby will be red for small (micrometer) or large crystals!
- However, when **one or more** dimensions are reduced down to the scale of the De Broglie wavelength of the carriers (e^- or h^+) in artificial structures, quantum confinement occurs
- De Broglie wavelength: $\lambda = \frac{h}{p}$
- A material can be considered a nanostructured material if some of the dimensions are less than 500 nm

Quantum confinement

- As a consequence of the low dimensions, higher surface areas are obtained but also introduce new physics and increased tunability of the electronic states
→ Discrete energy levels can appear



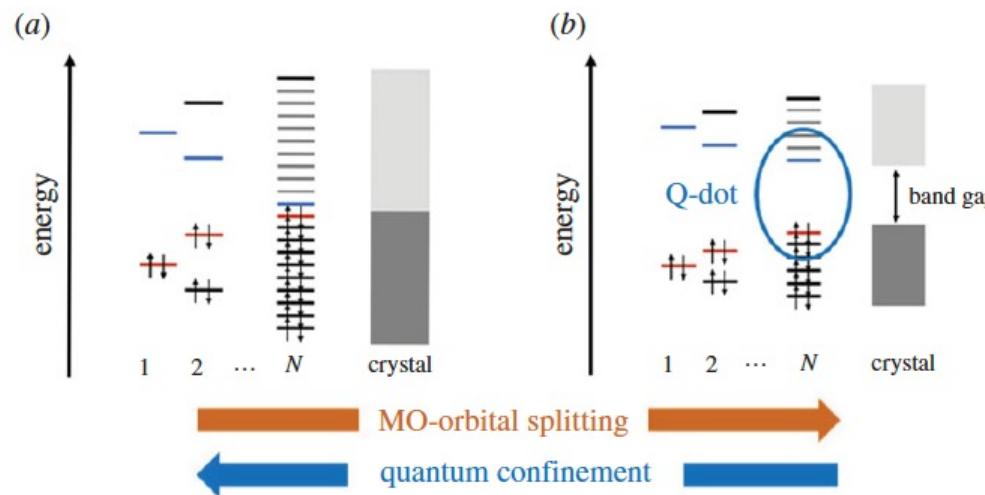
Structure	Quantum confinement	Number of free dimensions	Electron density of states
Bulk	none	3	$E^{1/2}$
Quantum well/superlattice	1-D	2	E^0
Quantum wire	2-D	1	$E^{-1/2}$
Quantum dot/box	3-D	0	discrete

Quantum confinement

- Heisenberg principle: $\Delta p_x \sim \frac{\hbar}{\Delta x}$
- Confinement gives an additional kinetic energy (*which increases the total E of the particle at rest*):
- This is equivalent to saying that Δx must be comparable to or smaller than the de Broglie wavelength $\lambda = \frac{h}{p}$ for the thermal motion
- At **RT**, we find that we must have $\Delta x < 5 \text{ nm}$ for an electron in a typical semiconductor
- Thus a “thin” semiconductor layer of $1 \mu\text{m}$ is not “thin” by the standards of the electrons -
→ It a bulk crystal without any quantum size effects except **at extremely low T**

...metals can become semiconductors!

- Striking effects in quantum-confined materials: Size dependence of the electronic states and thus also of the optical properties
- Ex: When a metal particle decreases in size and eventually becomes a cluster, discrete states are formed, with remarkable effects on the IR absorption for these structures
→ Require a quantum mechanical description that goes beyond the Drude model
- Sufficiently small metallic clusters more or less behave as semiconductors

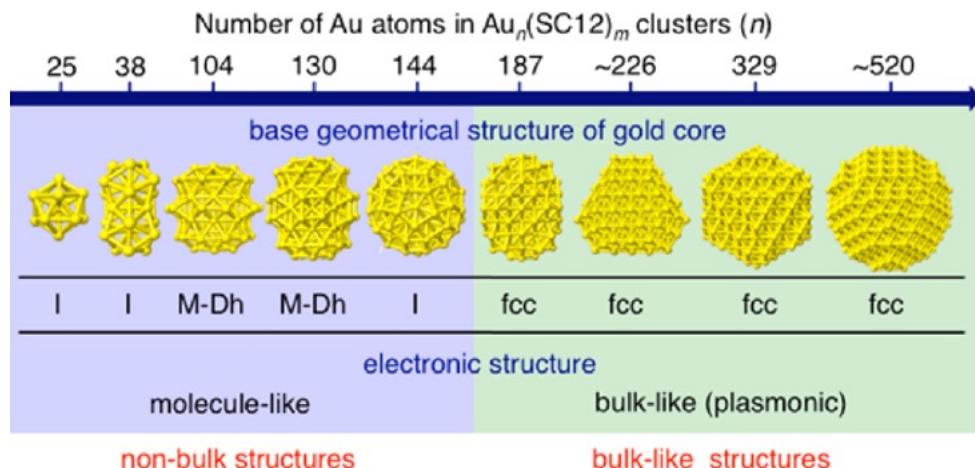


Schematic image of the quantum confinement effect in a metal (a) and a semiconductor (b).

...metals can become semiconductors!

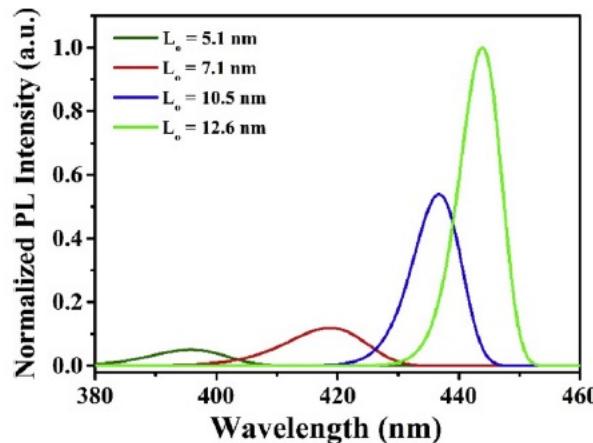
Ex: Gold nanoclusters

Transition between 144 and 187 atoms



Negishi et al., JACS, 2015, 137, 1206–1212

Photoluminescence can arise even in gold (but mechanism is not clear yet)

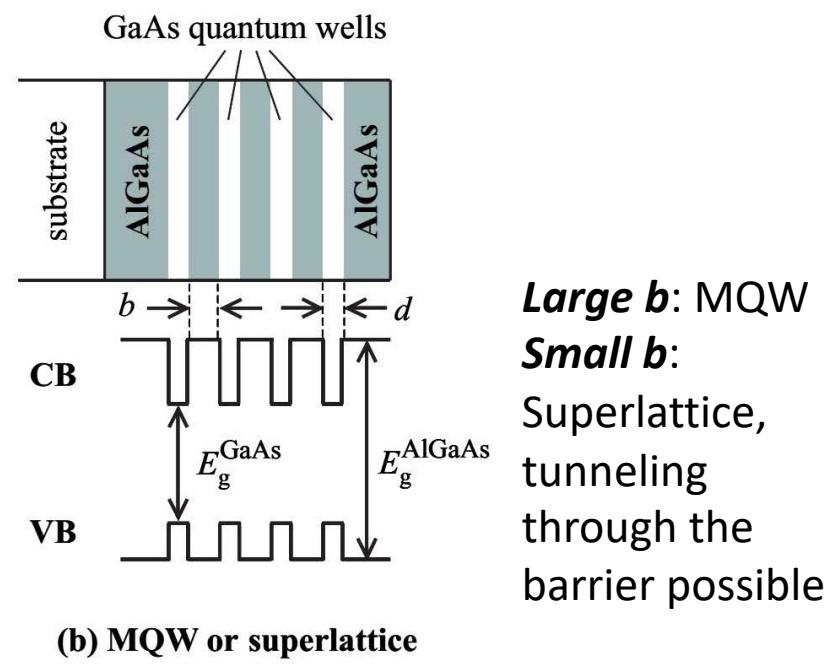
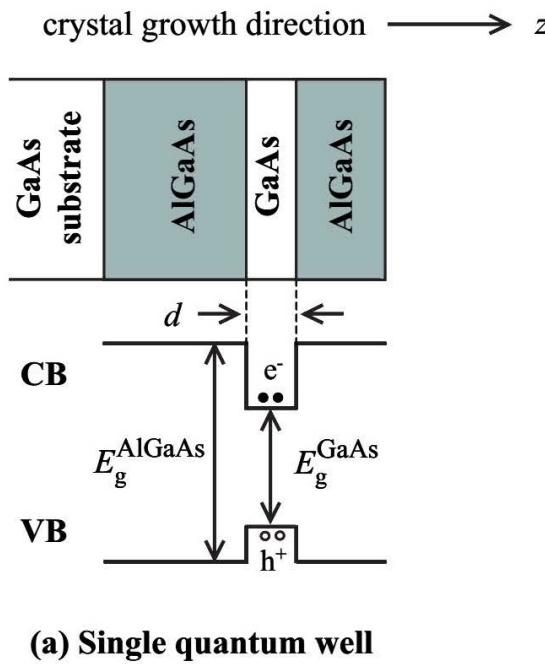


Alluhaybi et al., Optik – Int. J. Light and Electron Opt. 192
(2019) 162936

Quantum wells

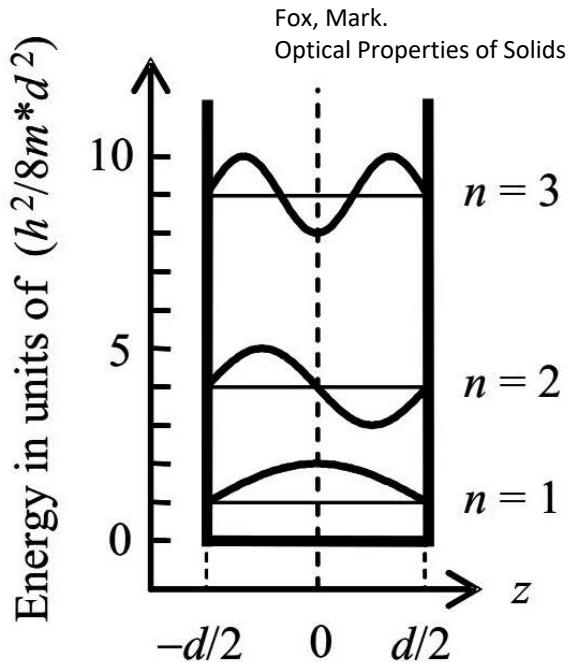
- Widely used in commercial opto-electronic devices (mainly electroluminescent devices)
- Heterostructure crystals made by techniques of advanced epitaxial crystal growth
→ Molecular beam epitaxy (MBE) or metal–organic chemical vapor deposition (MOCVD)
- Layer thickness can be controlled with atomic precision (possibility of multiple quantum wells, MQW)

Free motion in x,y planes
Trapped in z by potential barrier

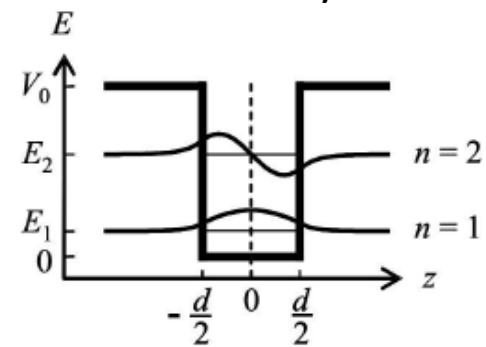


Used for optical applications:
Sizeable absorption

Particle in a box model



In reality:



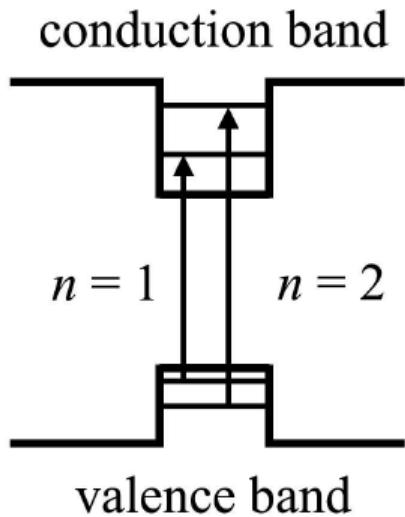
Particle in a box model

- The energy of the levels is inversely proportional to the effective mass and the square of the well width!

→ Low mass particles in narrow quantum wells have the highest energies

- Since the energy depends on the effective mass, the electrons, heavy holes, and light holes will all have different quantization energies

The QW will look like:

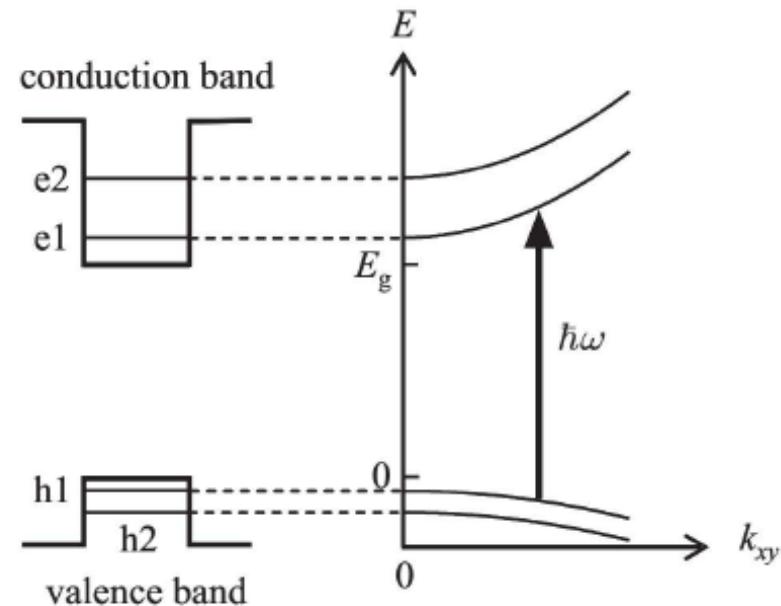


- In the valence band, the heavy holes will have the lowest energy, and are **dominant** in most situations because they form the ground-state level

Absorption in quantum wells

- Transition possible when exciting electrons from the ground state of the valence band ($n = 1$ heavy-hole level) to the lowest conduction band state (the $n' = 1$ electron level) ($\Delta n = 0$)

$$\begin{aligned}\hbar\omega &= E_g + E_{hh1} + \frac{\hbar^2 k_{xy}^2}{2m_{hh}^*} + E_{e1} + \frac{\hbar^2 k_{xy}^2}{2m_e^*} \\ &= E_g + E_{hh1} + E_{e1} + \frac{\hbar^2 k_{xy}^2}{2\mu}\end{aligned}$$



- For $\hbar k_{xy} = 0$ (analogous to the center of the Brillouin zone where $\hbar = 0$ in direct SC)

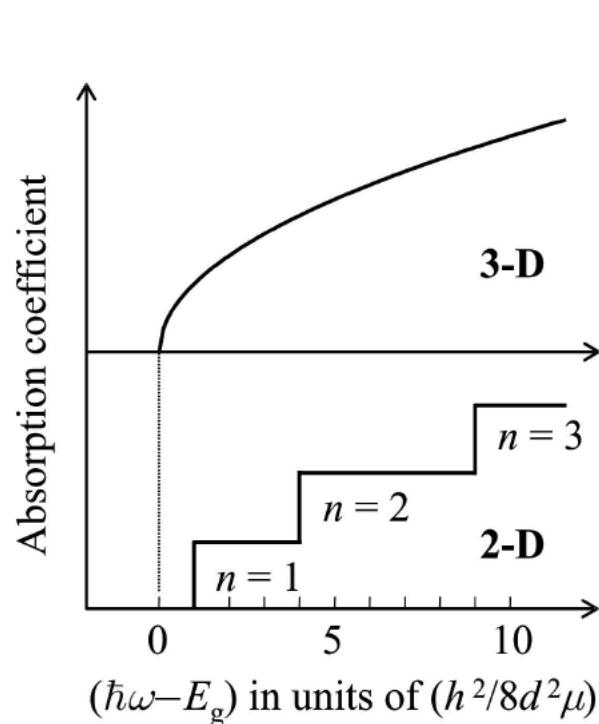
$$\hbar\omega = E_g + E_{hh1} + E_{e1}$$

- The optical absorption edge of the quantum well has been shifted by $E_{hh1} + E_{e1}$ compared to the bulk semiconductor

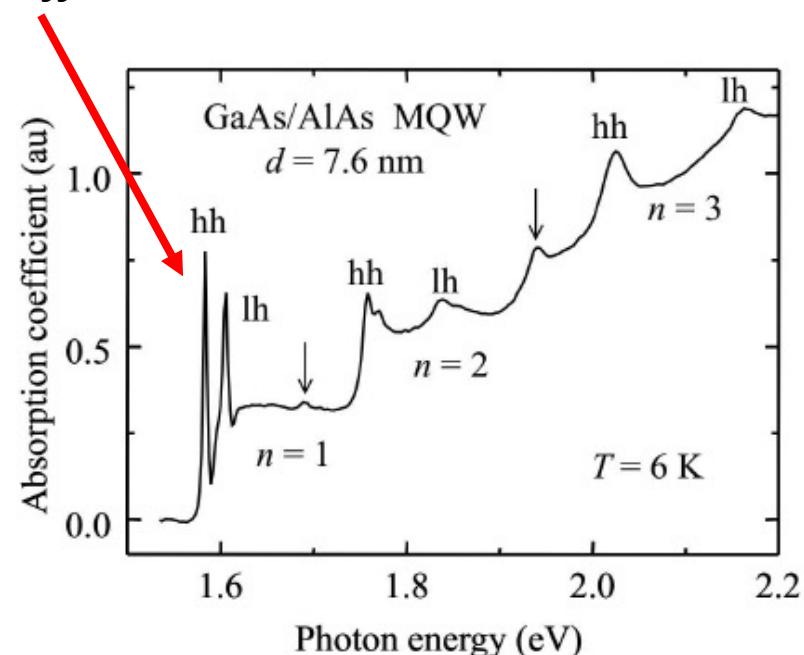
Absorption in quantum wells

- Since the confinement energies can be varied by choice of the well width, this gives a way to tune the frequency of the absorption edge!
- The argument can be repeated for the other allowed optical transitions in the QW
 → The next $\Delta n = 0$ transition for the heavy-hole states occurs at an energy of:

$$\hbar\omega = E_g + E_{hh2} + E_{e2}$$



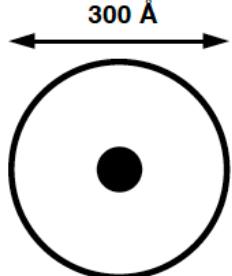
Excitonic effects



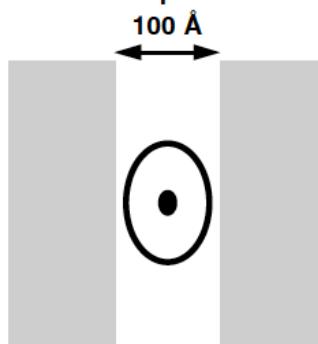
Excitons in quantum wells

- Reminder: We saw that usually excitons are delocalized in bulk SC and with low E
- Confined excitons are strong, can be stable at RT!
- The practical consequence is that in QW we may be able to make some use of the excitonic peaks at RT: Remarkable difference between bulk and confined!

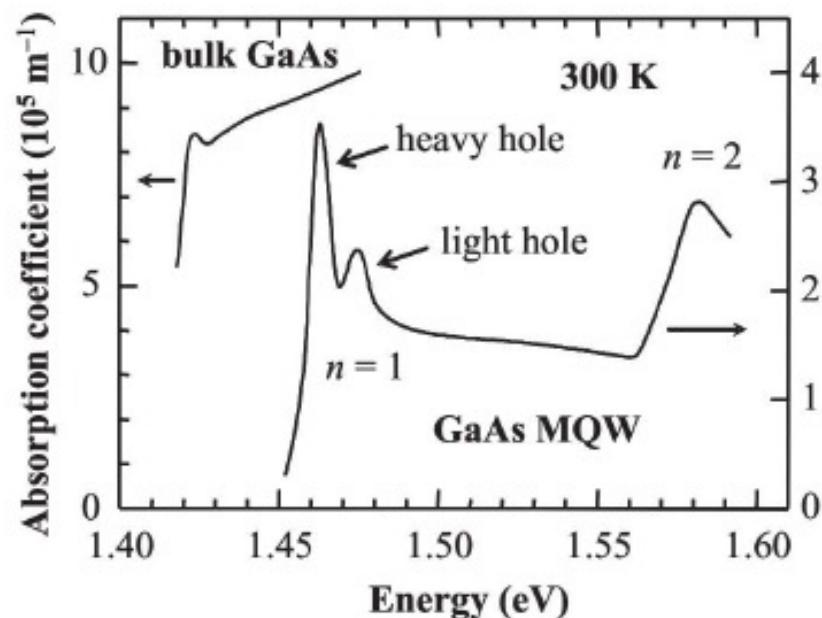
Exciton in bulk GaAs



Exciton in quantum well



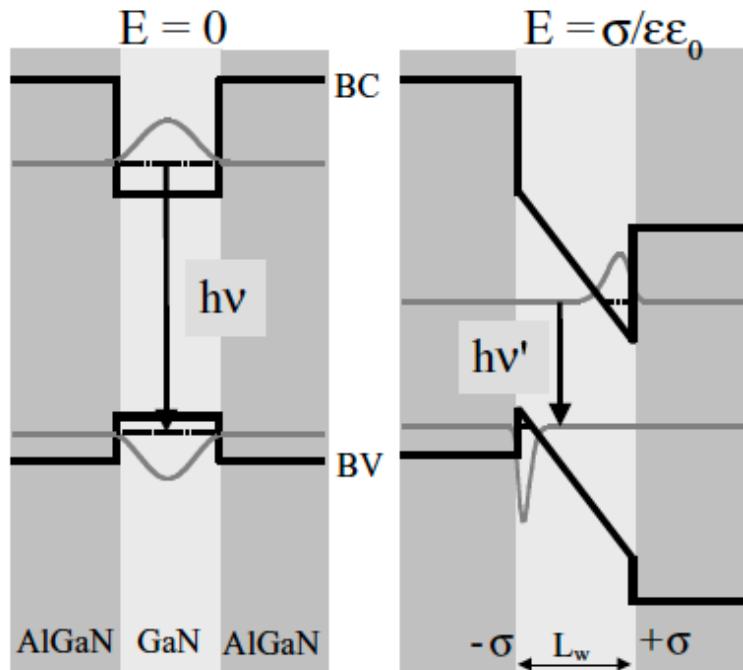
Miller, D., Optical Physics of Quantum Wells



Quantum-confined Stark effect

- In some materials, polarization linked to hexagonal structure (ex: wurtzite, GaN/AlN and InN/GaN) can generate very strong E fields up to 10-15 MV/cm
- When the field (external or due to polarization) is applied along confinement direction (z), it pushes e- and h⁺ in opposite directions, but the barriers prevent the exciton from breaking apart

→ The excitons are stable up to very high field strengths



Quantum-confined excitons interact with the field and shift to lower energy!

Application: Laser diodes

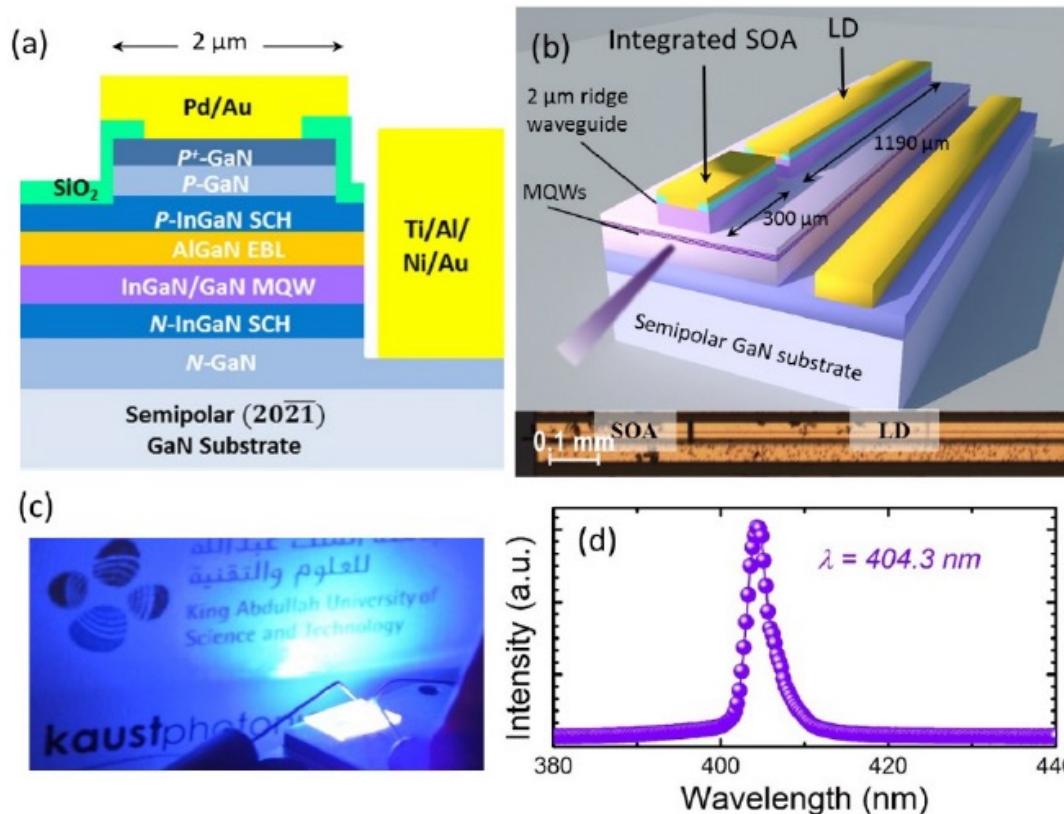
- Nitrides have remarkable properties and can cover the visible spectrum and UV!
- Bandgap: 1.9 eV for InN, 3.4 eV for GaN, 6.2 eV for AlN
- High stability for GaN
- Very good for blue LEDs and laser diodes (after solving the p-doping problem in the 1990s)

Laser diode material (active region / sub- strate)	Typical emission wavelengths	Typical application
InGaN / GaN, SiC	380, 405, 450, 470 nm	data storage
AlGaInP / GaAs	635, 650, 670 nm	laser pointers , DVD players
AlGaAs / GaAs	720–850 nm	CD players, laser printers, pumping solid-state lasers
InGaAs / GaAs	900–1100 nm	pumping EDFAs and other fiber amplifiers ; high-power VCSELs
InGaAsP / InP	1.2–2.0 μm	optical fiber communications, sensing, spectroscopy
AlGaAsSb / GaSb	1.8–3.4 μm	defense, sensing, spectroscopy

Table 1: Emission wavelengths of various common types of laser diodes.

Application: Laser diodes

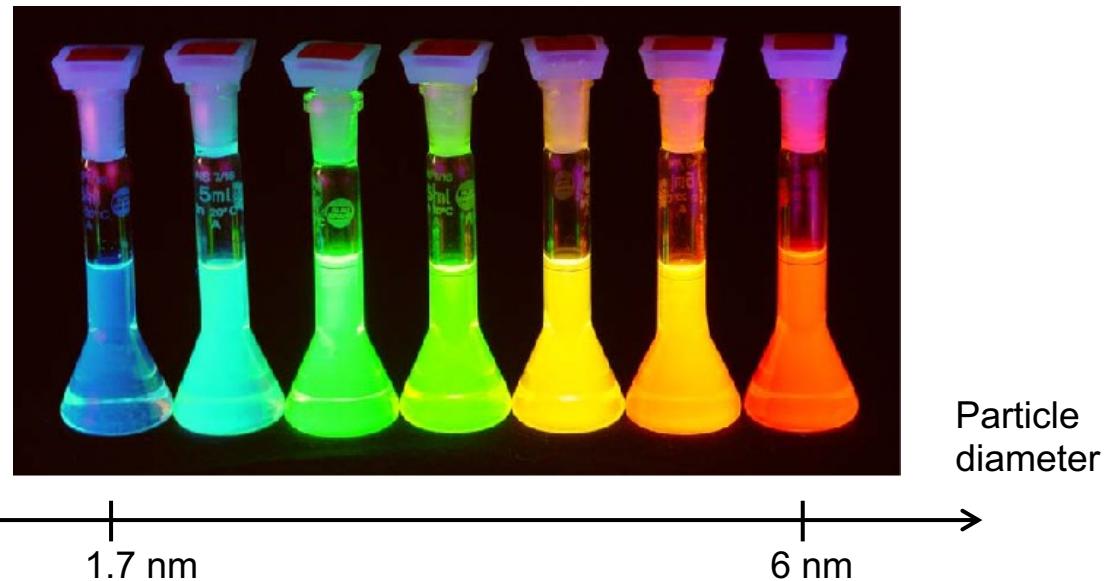
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6.2 Quantum dots (also called semiconductor nanocrystals)

Size matters, again!

CdSe-CdS core-shell nanoparticles with various diameters



$$E_{nl} = \frac{\hbar^2}{2m^*} \frac{C_{nl}\pi^2}{R_0^2}$$

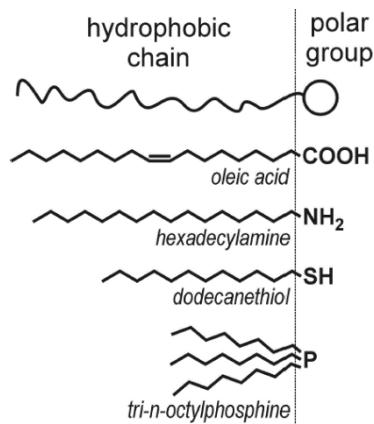
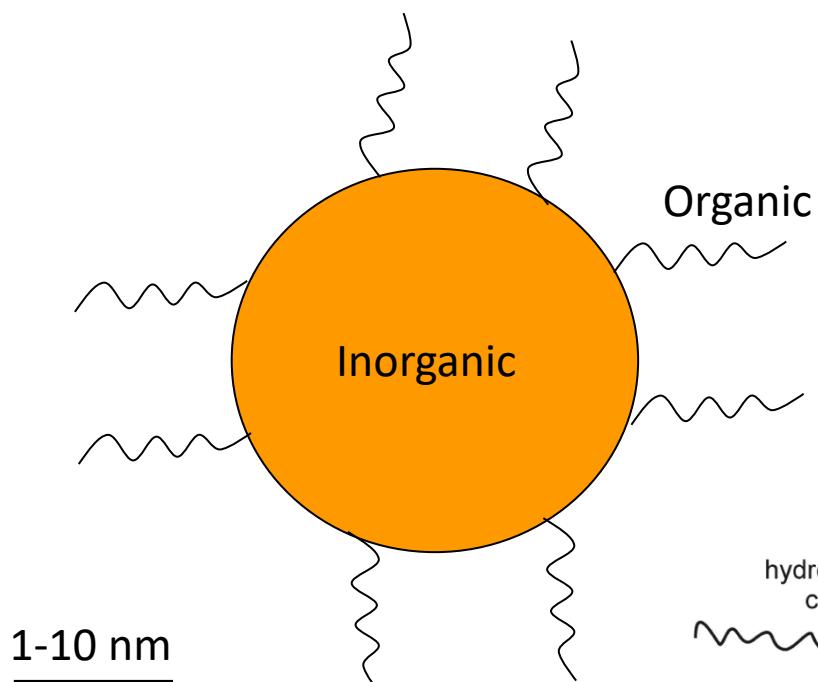
E. Roduner, *Size matters: why nanomaterials are different*, Chem. Soc. Rev., 2006, 35, 583–592

- Quantum dots can be made by lithographic patterning of quantum wells

OR

- Colloidal synthesis of quantum dots or nanoplatelets using organic precursors, surfactants and solvents

QDs : Inorganic Nanocrystals



Inorganic:

MX

where M: Pb, Cd and X: S, Se

Like **PbS, CdS or PbSe**

... and many more possibilities!

Around 200 – 10000 atoms

Organic:

Surfactant monolayer (or ligands)

- Anchoring part

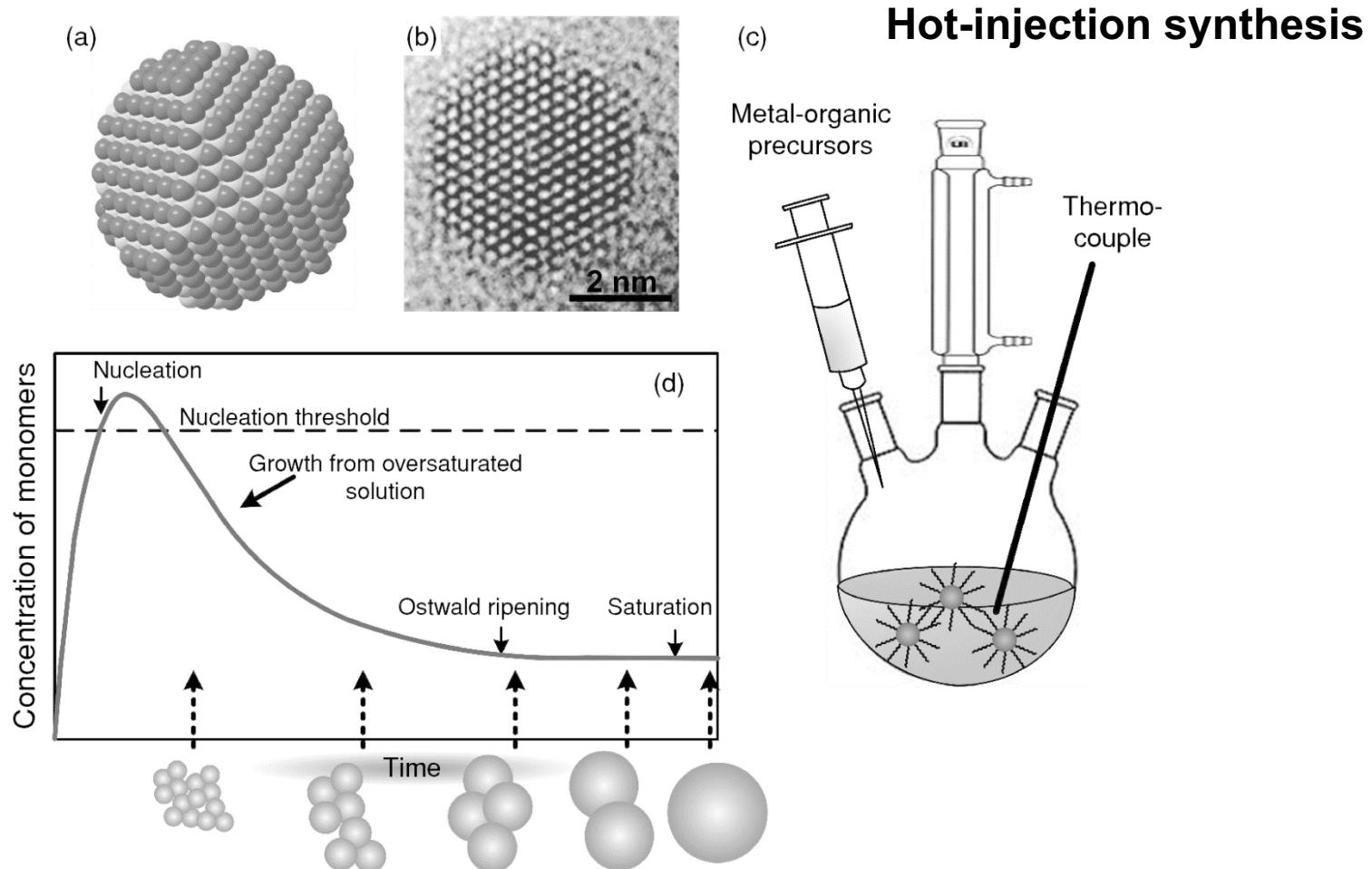
- Hydrophobic part

Role of ligands:

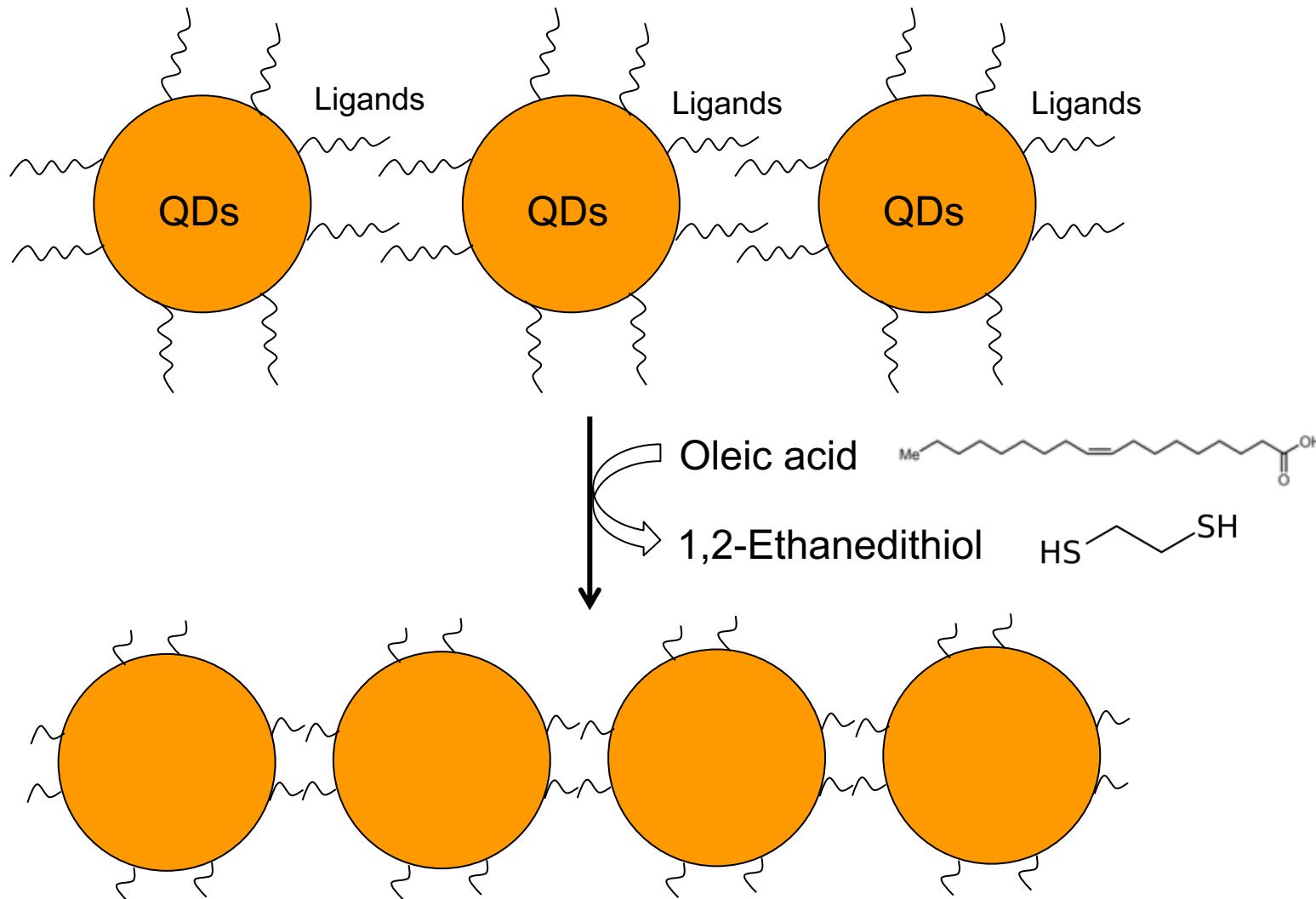
(1) Monodispersity of QDs (2) Preventing agglomeration (3) Defect passivation

Alternative to ligands: Inorganic shells (but less flexibility in design)

QDs synthesis

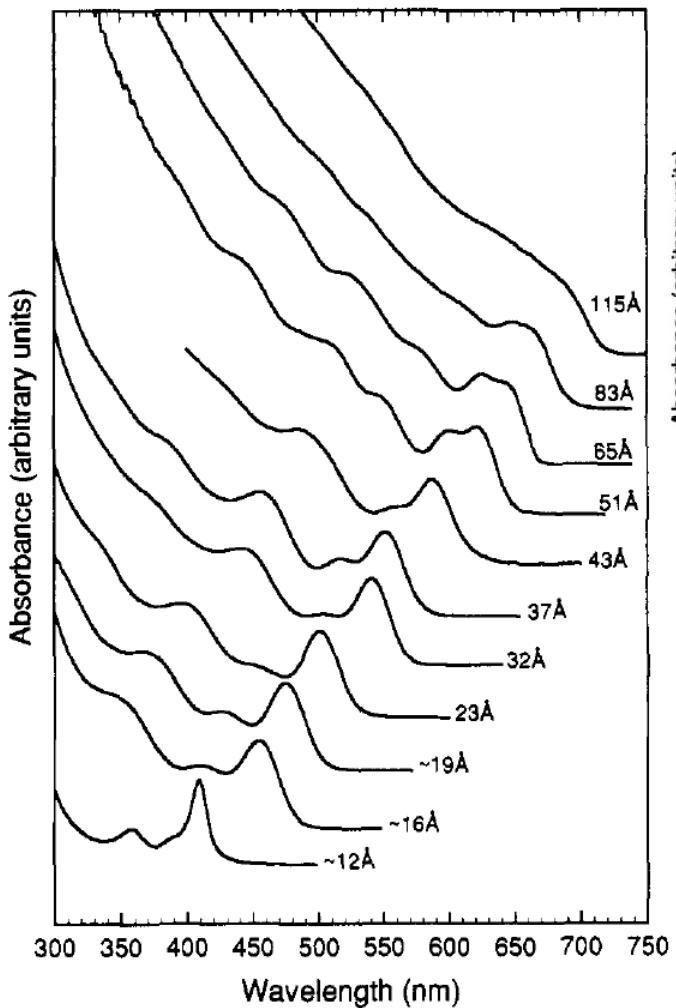


Ligand exchange: Functionalization

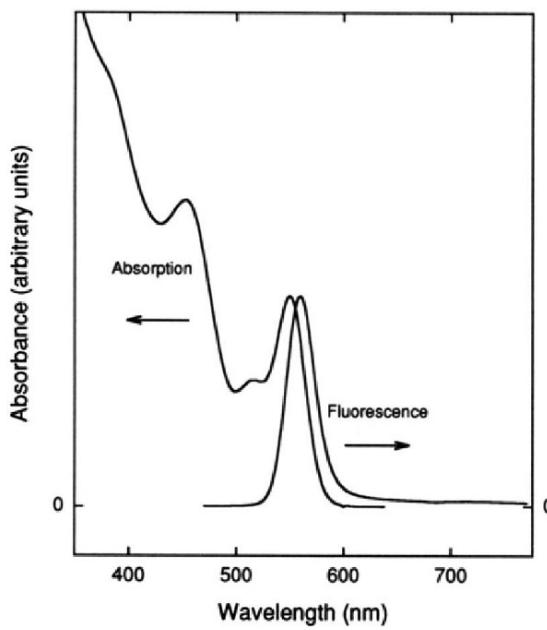


Potential of QDs

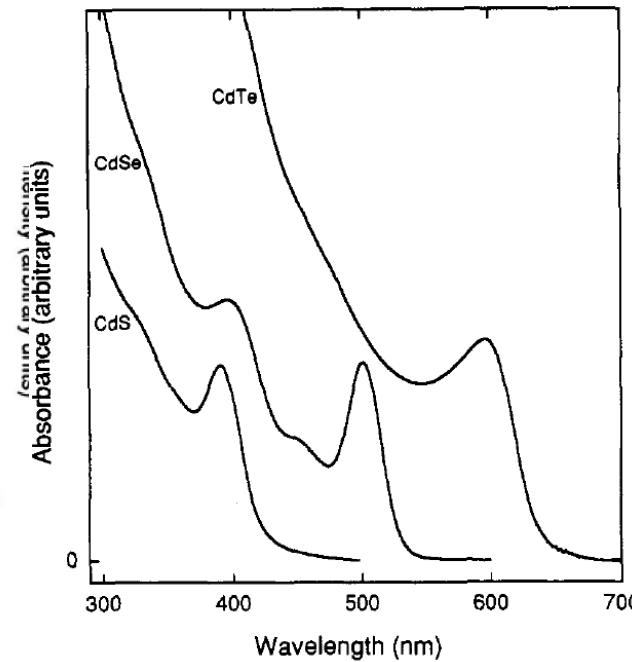
Size effect (CdSe)



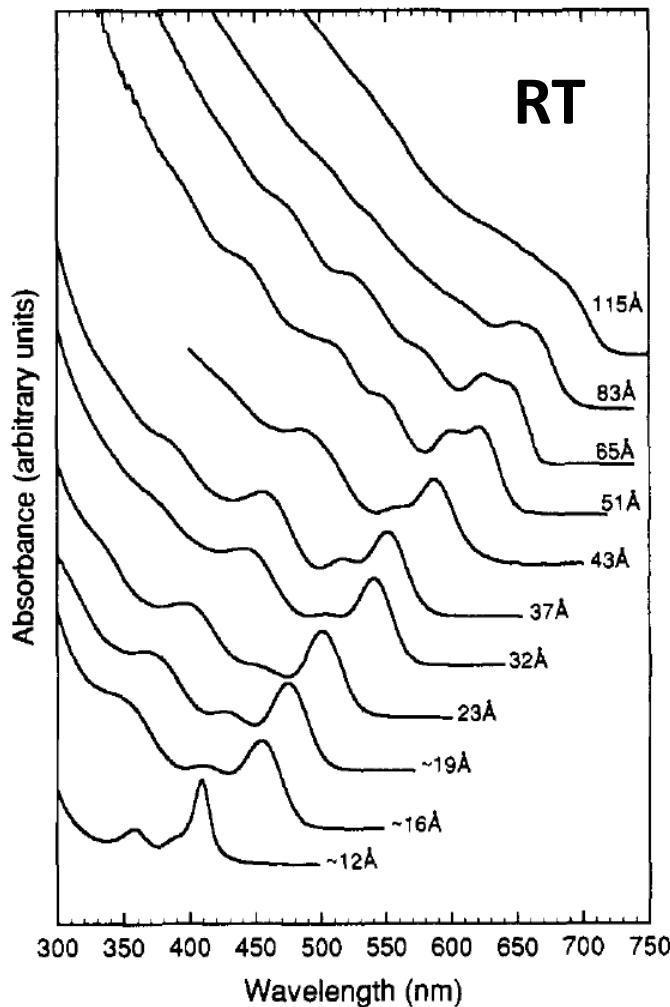
Narrow PL



Band edge tunability



Absorption in QDs: Size effect



CdSe QDs dispersed in hexane

$$\hbar\omega = E_g + E_{nl} - E_{ex}$$

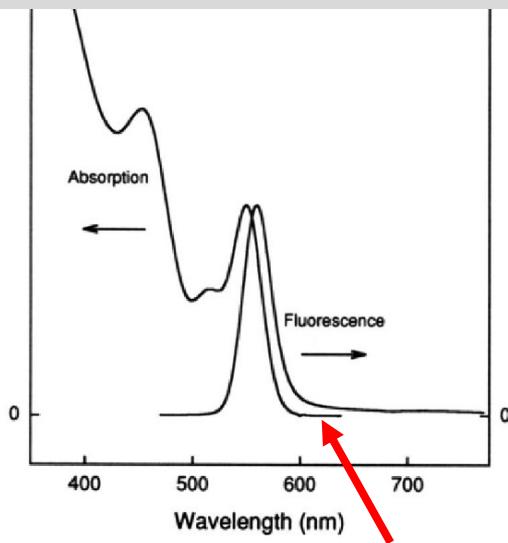
$$= E_g + \frac{2\hbar^2 \pi^2}{\mu} \frac{1}{R_0^2} - E_{ex}$$

- A large part of the “art” of making colloidal quantum dots is obtaining a good size distribution
- Usually, the standard deviation of the diameters of the dots can be < 5%

Absorption in QDs: Narrow PL

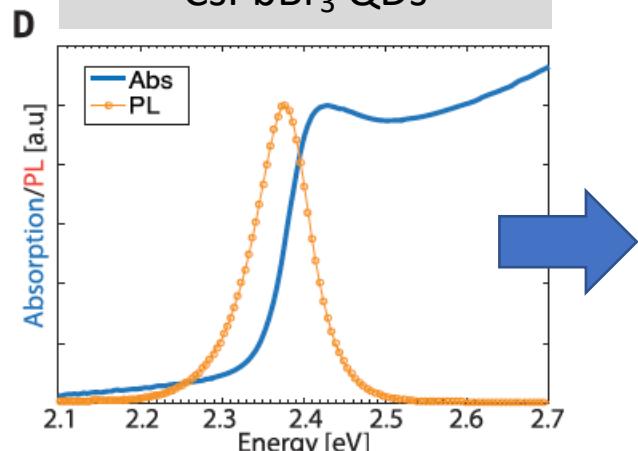
- By confining the carriers in 3D, we increase the e-/h⁺ overlap and increase the radiative quantum efficiency → **very high QY can be achieved!!**
- The discrete nature of the density of states reduces the thermal spread of the carriers

RT band edge luminescence for $d = 35 \text{ \AA}$ CdSe crystallites

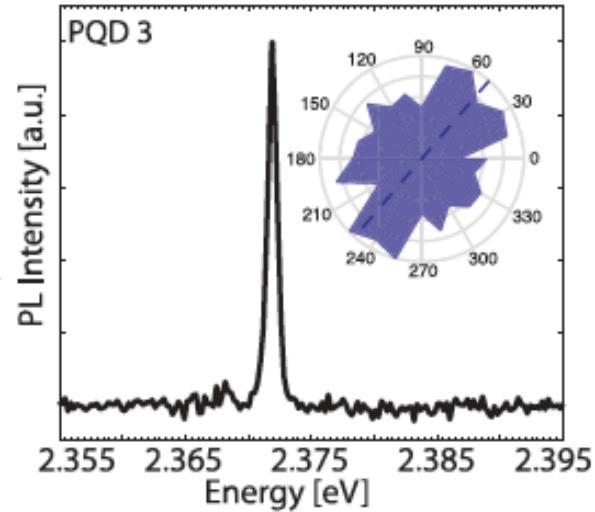


And obviously...
Perovskite make great
QDs emitters!

Ensemble spectra of
CsPbBr₃ QDs



As a **single particle**:
No broadening from
inhomogenous size
distribution



No deep trap luminescence detected!

Utzat et al., Science 363, 1068–1072 (2019)

Absorption in QDs: Narrow PL

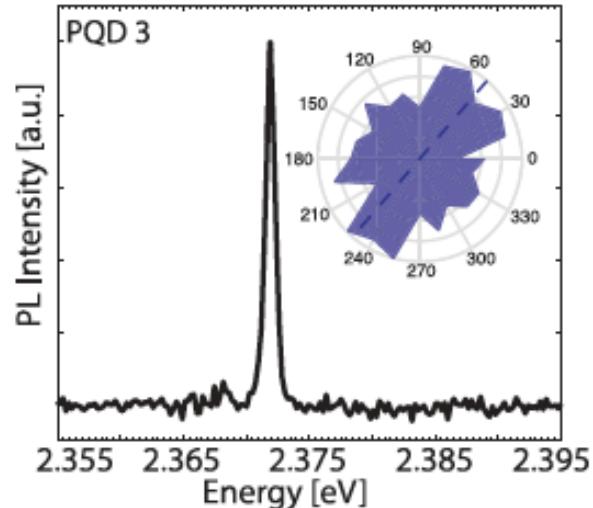
- By confining the carriers in 3D, we increase the e-/h⁺ overlap and increase the radiative quantum efficiency
- The discrete nature of the density of states reduces the thermal spread of the carriers

As a single particle: No broadening from inhomogenous size distribution

- The width of the exciton line from a single quantum dot is ultimately limited by the radiative lifetime!

$$\Delta E \Delta \tau \geq \frac{\hbar}{2}$$

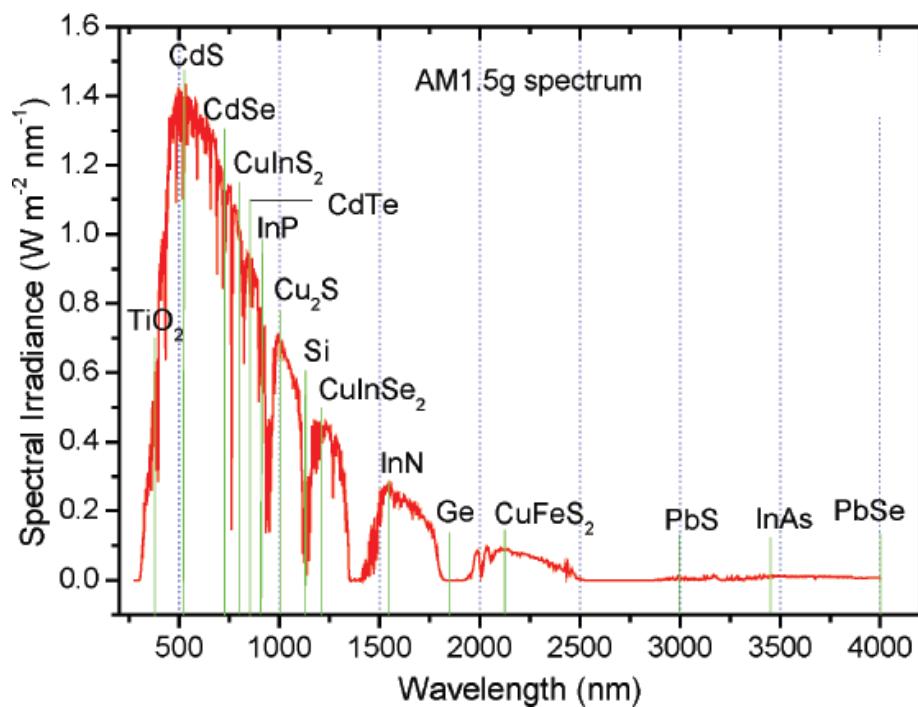
- With typical values of radiative lifetimes $\sim 1\text{ns}$, linewidths as small as a few μeV have been observed



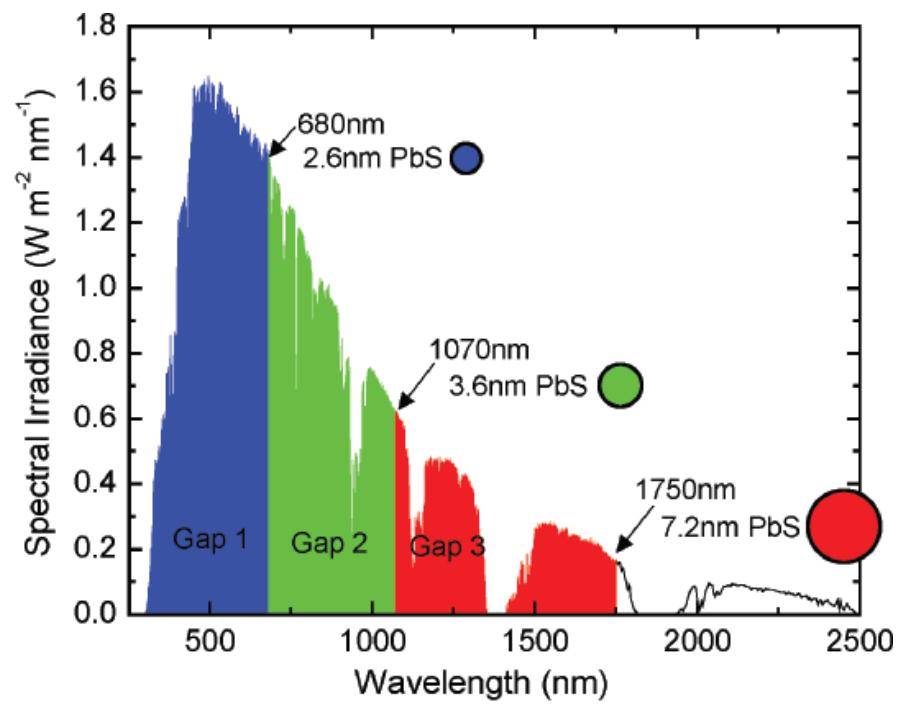
Utzat et al., Science 363, 1068–1072 (2019)

Absorption in QDs: Band gap tunability

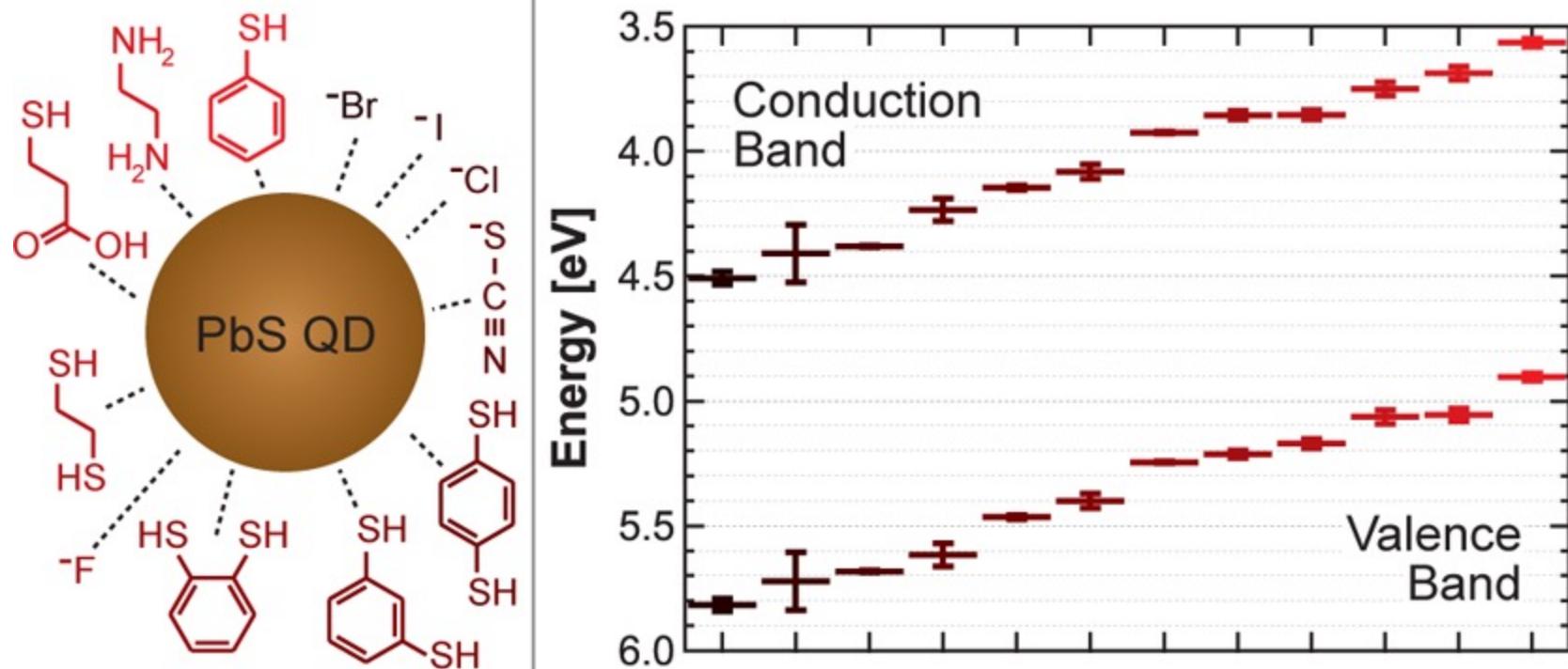
Changing the material of NCs



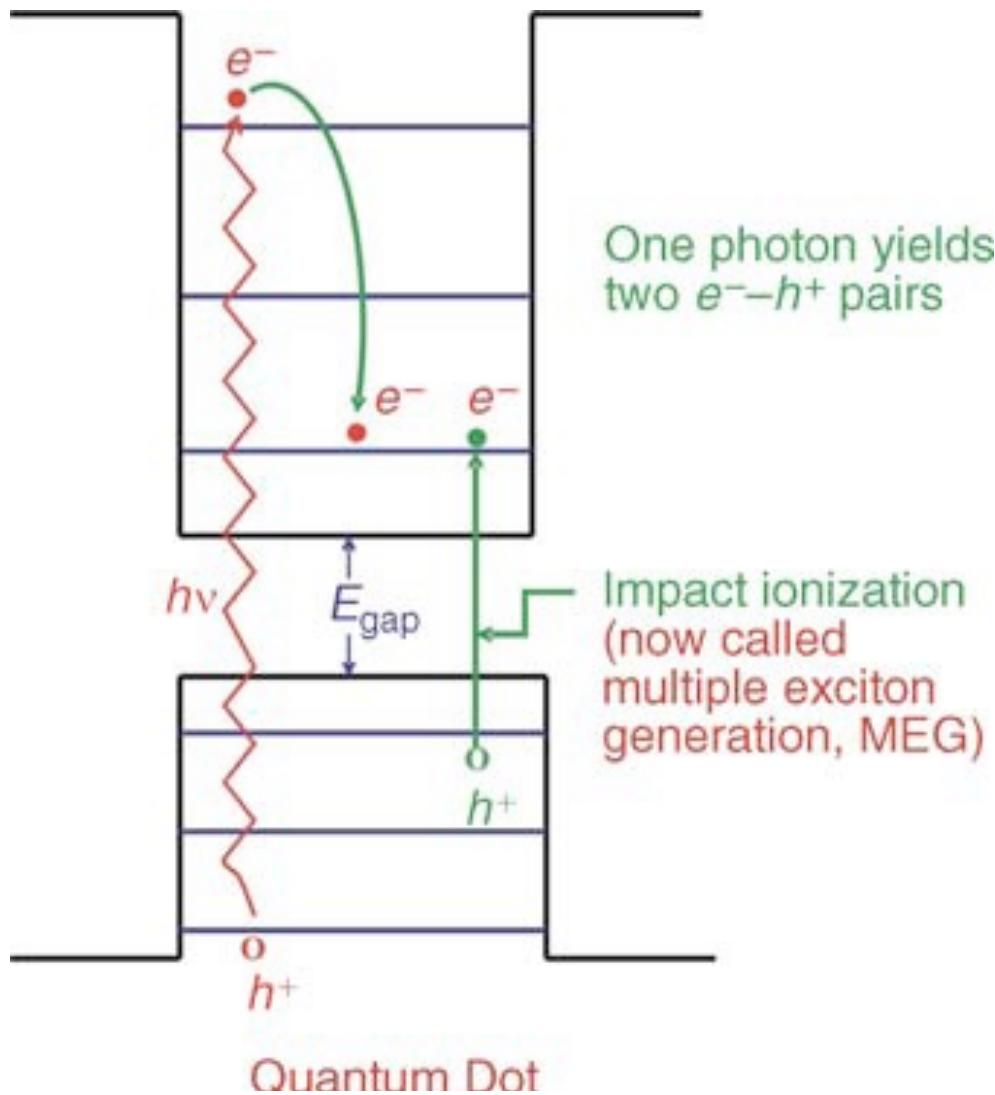
Changing the radius of NCs



Absorption in QDs: Energy level alignment from ligand exchange

Brown et al. *ACS Nano* **8**, 5863 (2014)

Multiple-exciton generation in QDs



Released excess energy does not go into a phonon but excites another electron across the bandgap!

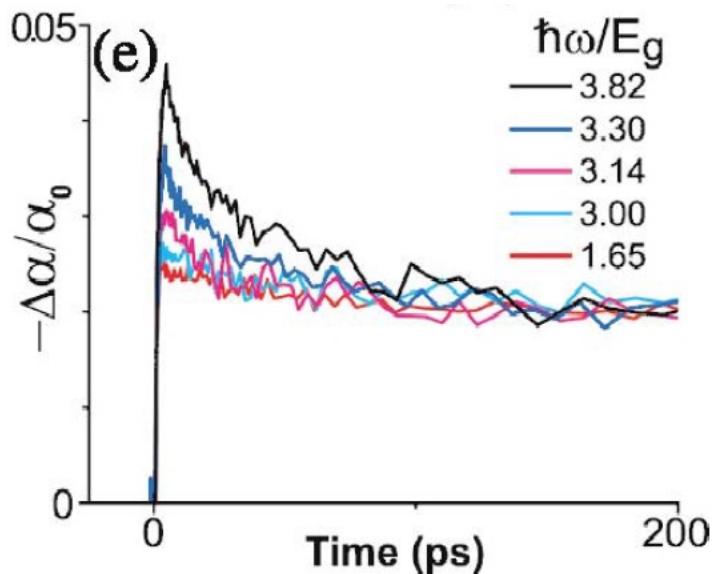


One photon creates 2, 3, or more e^-/h^+ pairs

→ Quantum efficiency of 200-300-400% possible!

Probing MEG with TA

- Colloidal PbSe NC samples with absorption maxima at 0.86 eV (~ 1400 nm) for the lowest transition
- Normalized pump-induced bleaching of the lowest transition
- Bleaching has an additional component at higher energies above the bandgap: MEG takes place on an ultrafast (picosecond) time scale
- Even with only ~ 10 -100 ps lifetime of biexcitons observed here, MEG can still be useful for solar power generation!



Schaller, Klimov, *Phys. Rev. Lett.* **2004**, 92, 186601

Design of „real“ QD solar cells

